

Introduction to Nanotechnology

Kuei-Hsien Chen: IAMS, Academia Sinica & CCMS, NTU

Ph.D. 1989 Harvard University

Hossein hosseinkhani: GIBE, NTUST

Ph.D. Kyoto University

Chunwei Chen: MSE, NTU

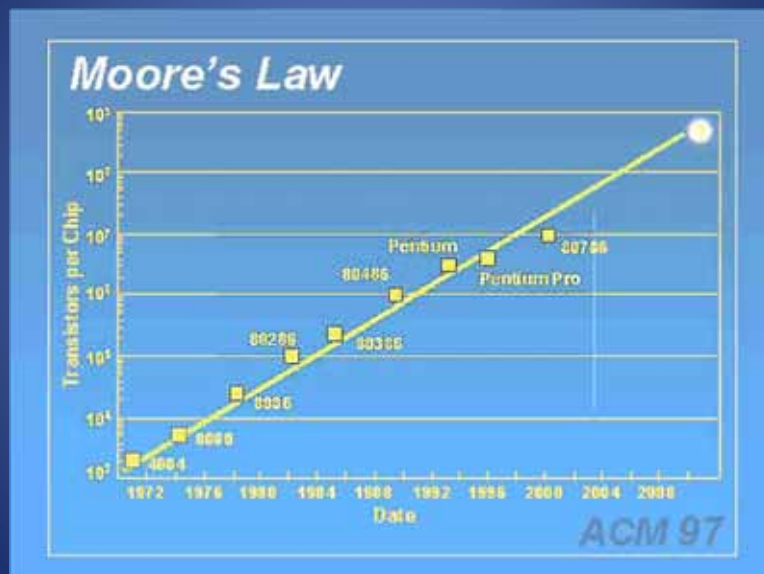
Ph.D. Cambridge University

Li-Chyong Chen: CCMS, NTU

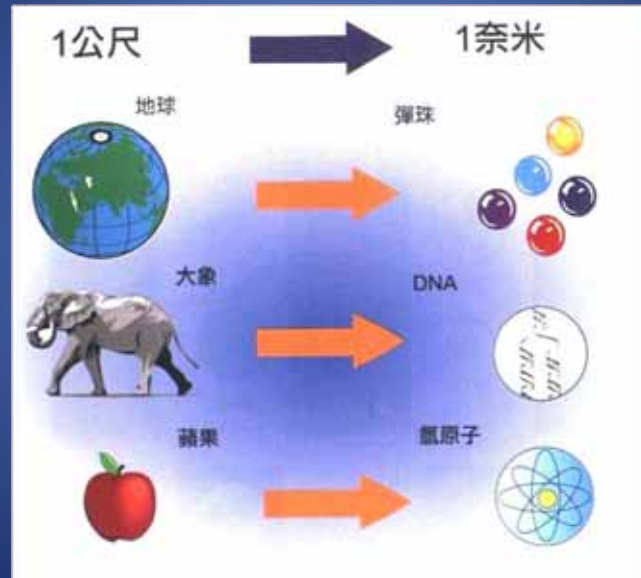
Ph.D. 1989 Harvard University



Moore's Law



What is Nano?



Scale

- Meter (m)
- Millimeter (mm) = 10^{-3} m
- Micrometer (μm) = 10^{-6} m
- Nanometer (nm) = 10^{-9} m
- Picometer (pm) = 10^{-12} m
- Femtometer (fm) = 10^{-15} m
- Attometer (am) = 10^{-18} m ?
- Second (s)
- Millisecond (ms) = 10^{-3} s
- Microsecond (μs) = 10^{-6} s
- Nanosecond (ns) = 10^{-9} s
- Picosecond (ps) = 10^{-12} s
- Femtosecond (fs) = 10^{-15} s
- Attosecond (as) = 10^{-18} s

Pressure

- $1 \text{ Pa} = 1 \text{ Nm}^{-2} = 10^{-5} \text{ bar} = 7.501 \times 10^{-3} \text{ mm Hg (torr)}$
- $1 \text{ atm} = 760 \text{ mm Hg} = 1.013 \text{ bar}$

Energy

- $1 \text{ cal} = 4.184 \text{ J}$
- $1 \text{ eV} = 1.602 \times 10^{-19} \text{ J} = 23.06 \text{ kcal/mole}$
- $1 \text{ kWh} = 3.6 \times 10^6 \text{ J}$
- $1 \text{ BTU} = 1055 \text{ J}$

Power

- $1 \text{ W} = 1 \text{ Js}^{-1}$
- $1 \text{ hp} = 746 \text{ W}$

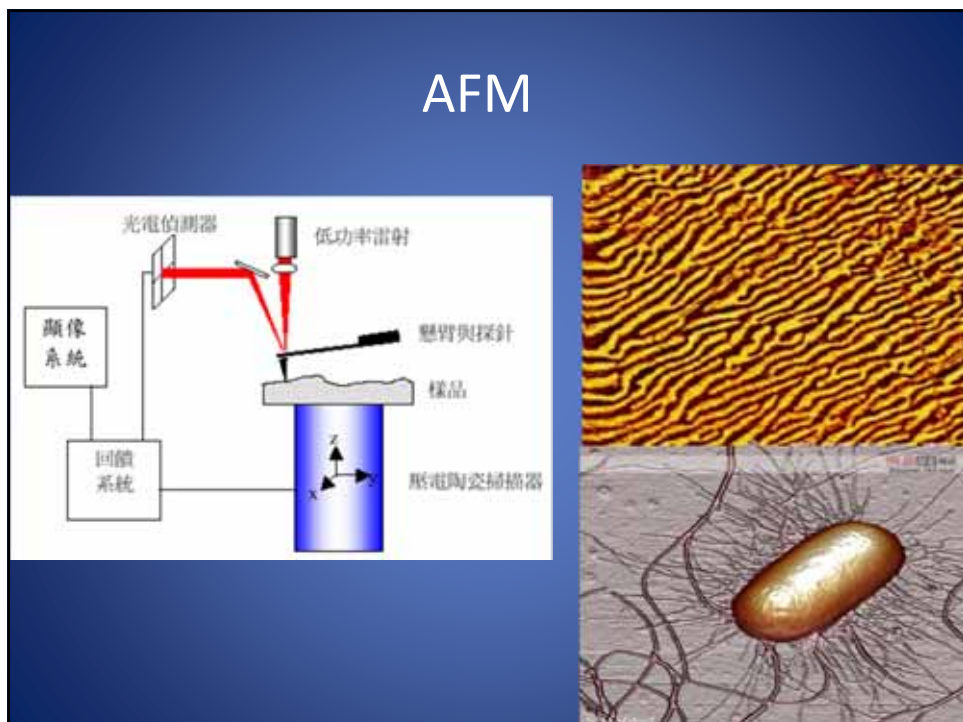
SEM



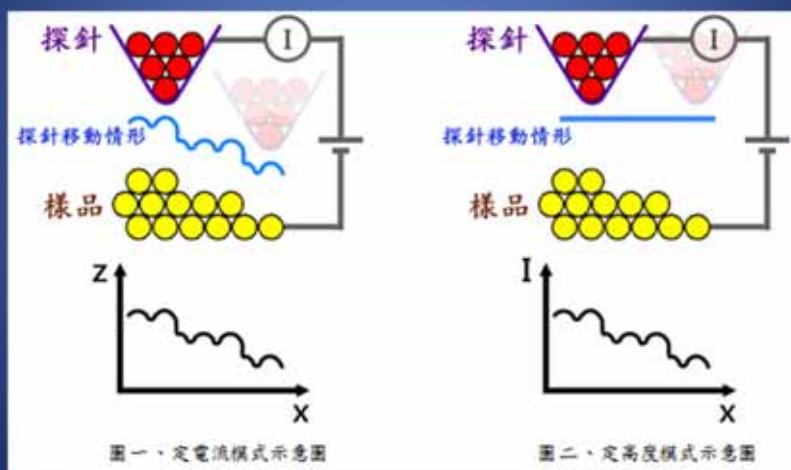
SEM



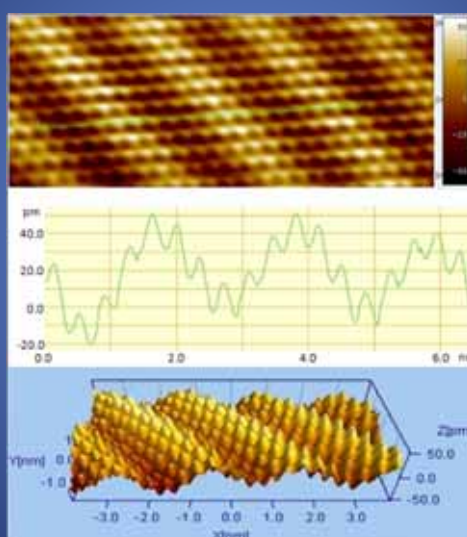
AFM



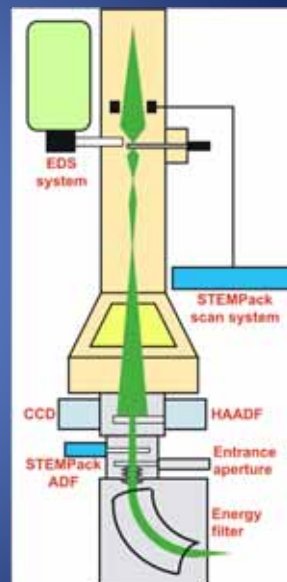
STM



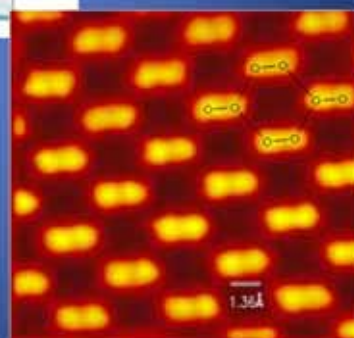
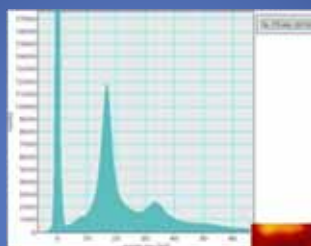
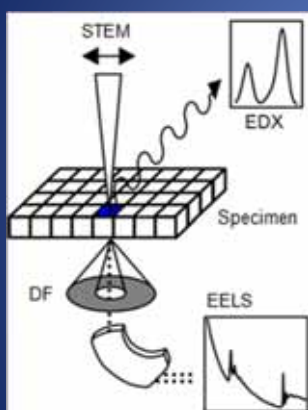
STM



TEM



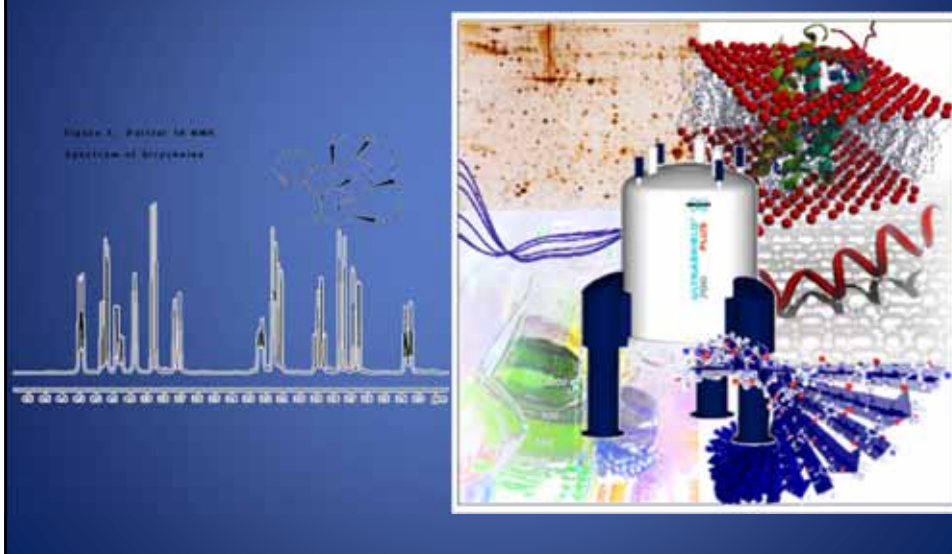
TEM (EELS)



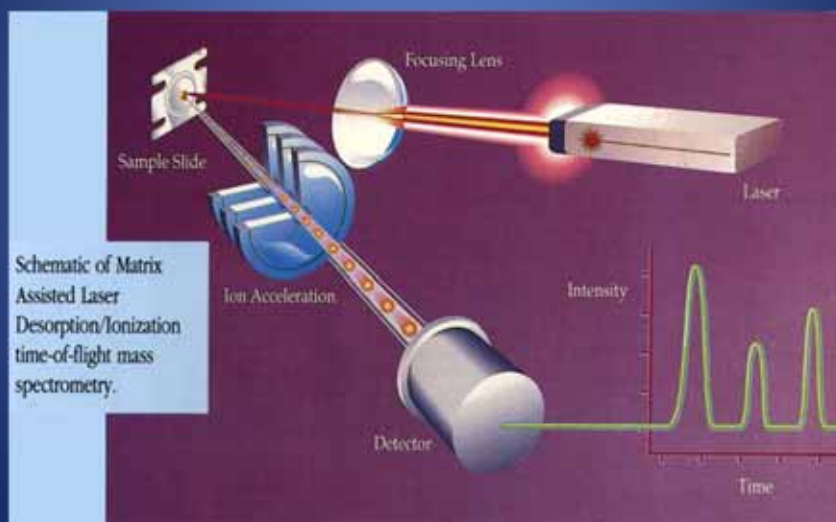
Composition Analysis

1. EL (元素分析儀)
2. EDS (X射線能量散佈分析儀)
3. AES (歐傑電子光譜)
4. NMR (核磁共振波譜分析)
5. ICP MASS (電子耦合電漿質譜)
6. MALDI (Matrix-assisted laser desorption/ionization)

NMR, MRI



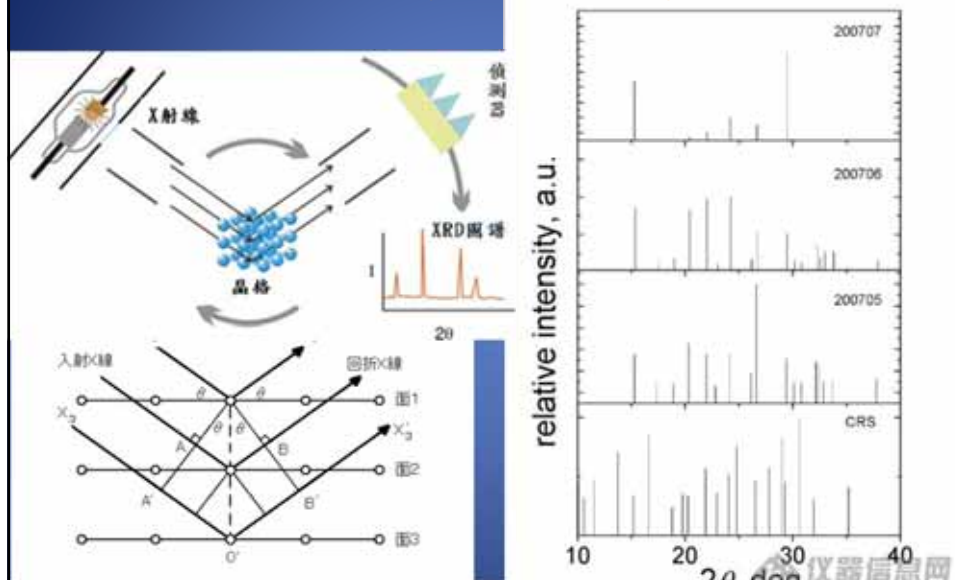
MALDI (Matrix-assisted laser desorption/ionization)



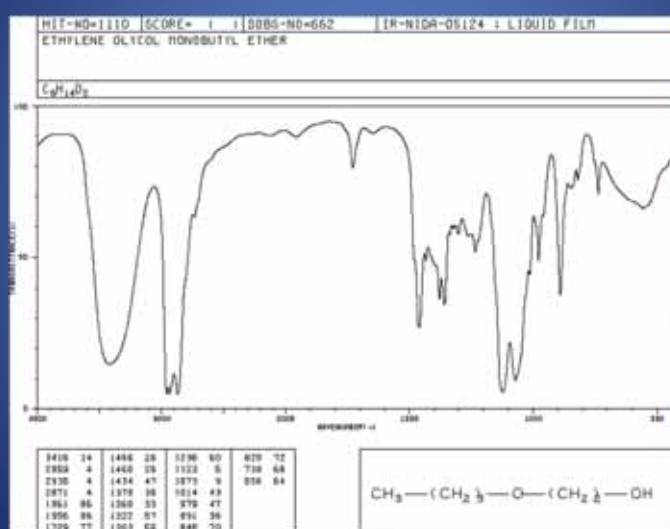
Structure Analysis

1. XRD (X光繞射)
2. TEM (穿透式電子顯微鏡)
3. FTIR (紅外光譜)
4. Raman (拉曼光譜)

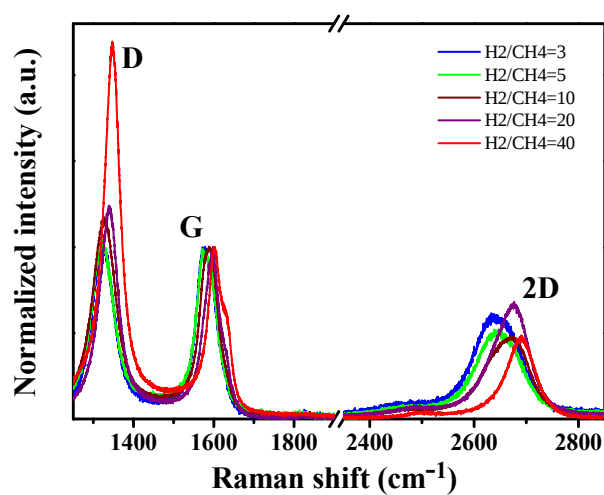
XRD (X光繞射)



FTIR (紅外光譜)(鍵結)



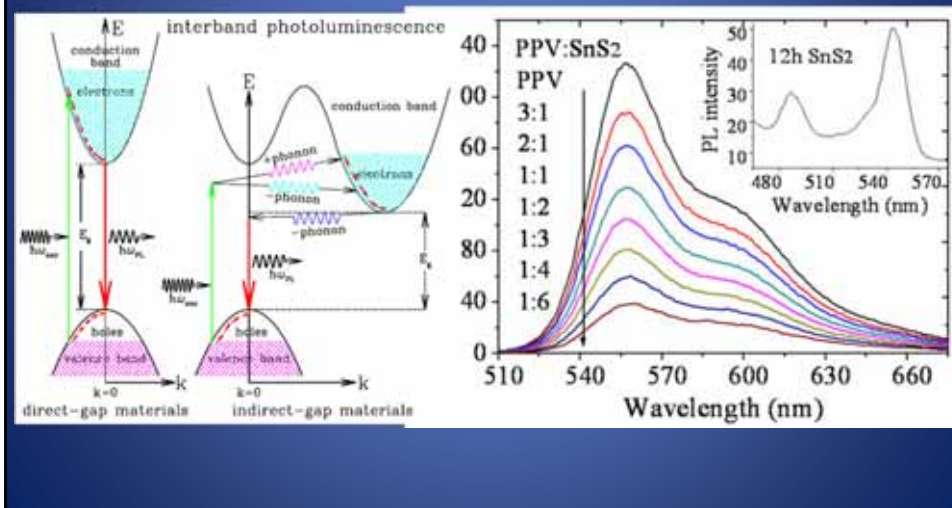
Raman (拉曼光譜)



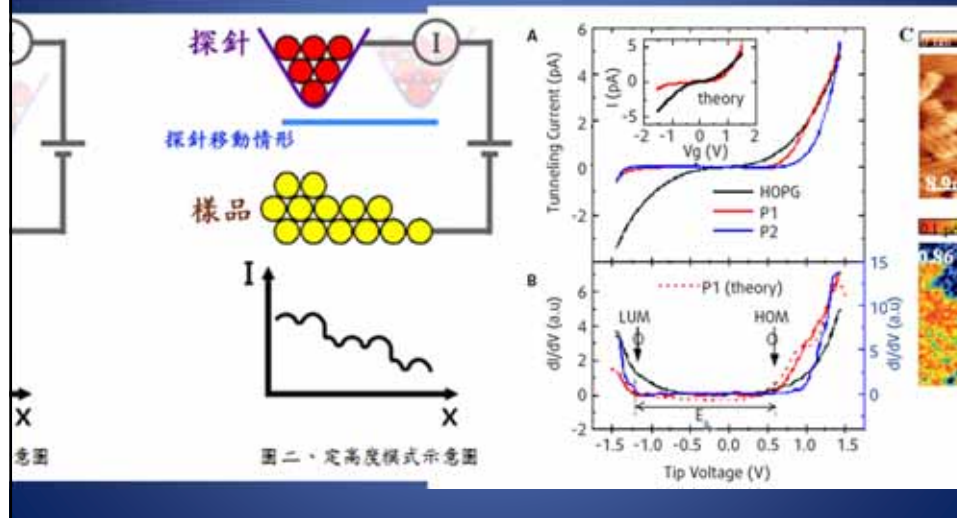
Electronic properties

1. Optical Absorption (吸收光譜)
2. Photoluminescence (螢光光譜)
3. STS (掃描穿隧顯微術)
4. XPS (X光電子光譜)
5. 同步輻射測量(SRRC)

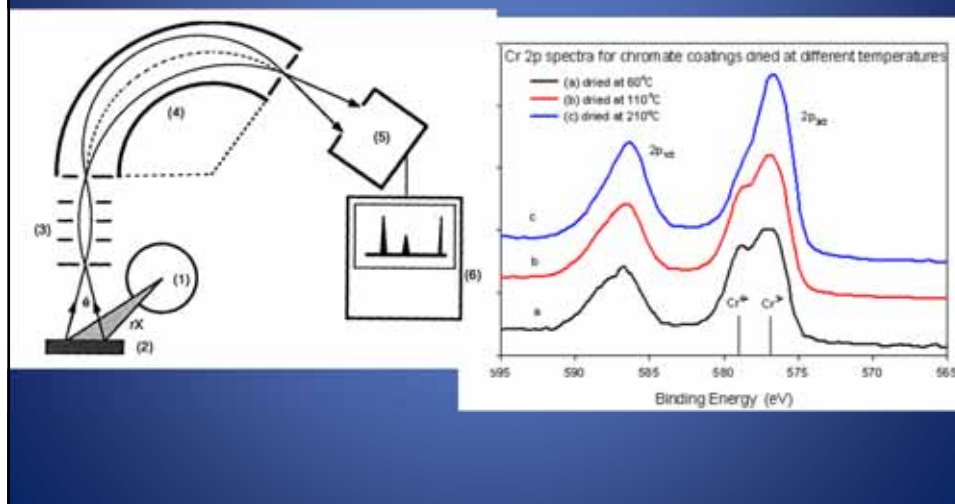
Photoluminescence (PL & CL)



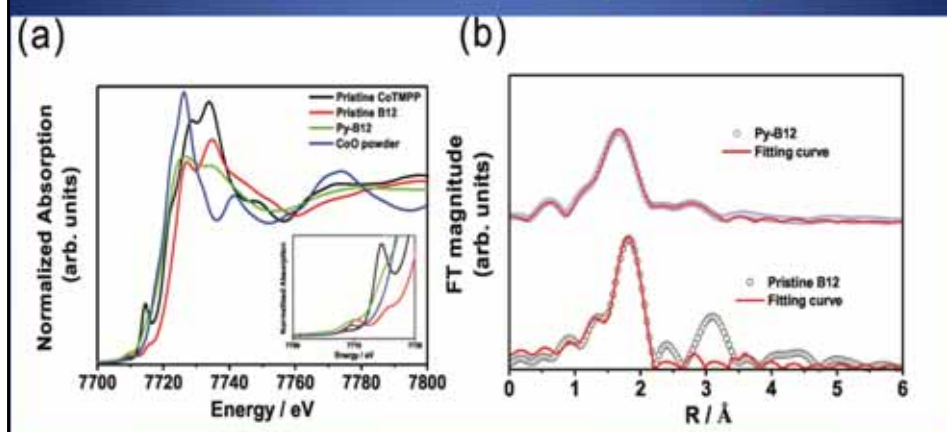
STS (掃描穿隧顯微術)



XPS (X光電子光譜)



同步輻射測量(SRRC)

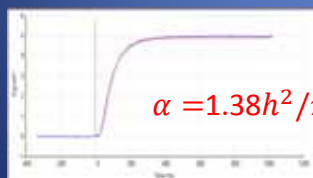
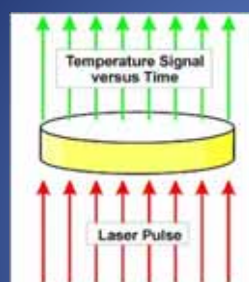


(XANES & EXAFS)

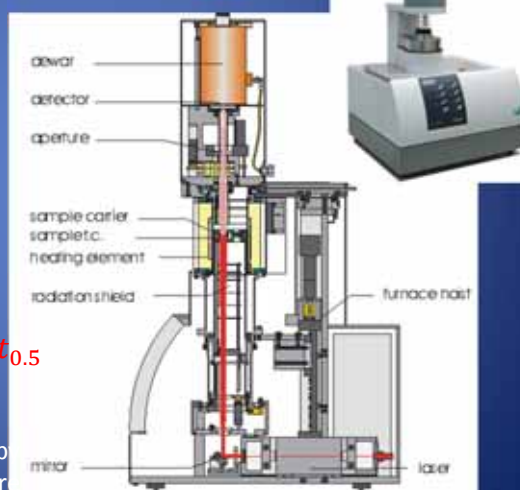
Other Thermal and Magnetic Measurements

1. 熱傳導係數測量(Thermal conductivity)
2. 熱重分析(TGA)
3. 熱分析儀 (DSC)

Thermal Diffusivity Measurement

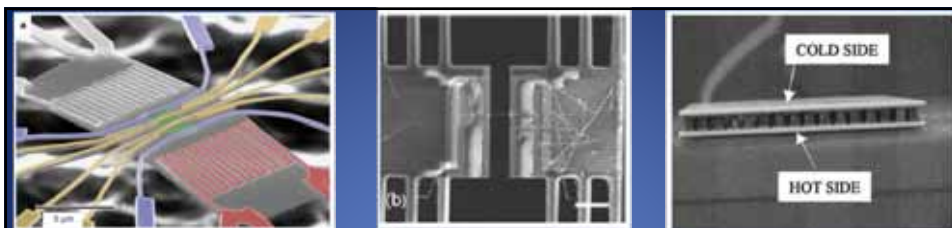
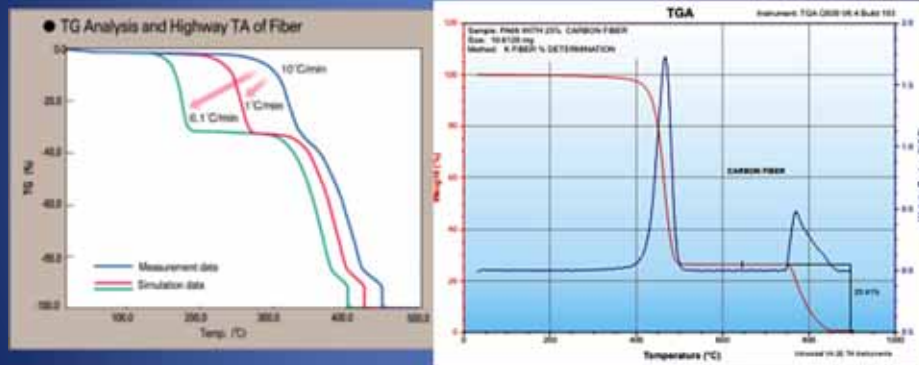


We can get the thermal diffusivity by measure the “half-time” of temperature increase resulted from laser heating.

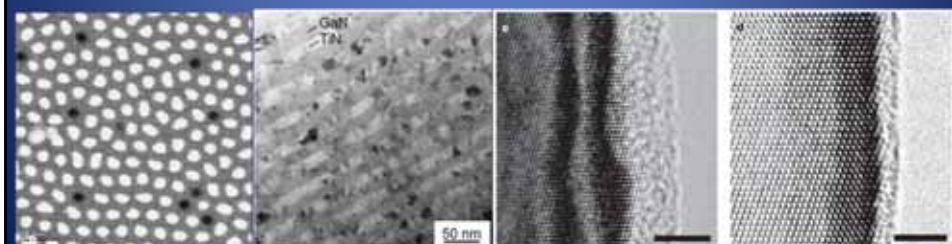


Cooperator: Dr. Y. Chen's lab

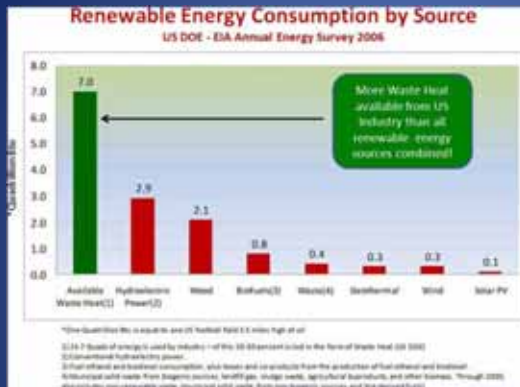
TGA & DSC



Nanomaterials for Thermoelectric Applications



Renewable Energy



Solar



Wind



Water



Biomass



Geothermal

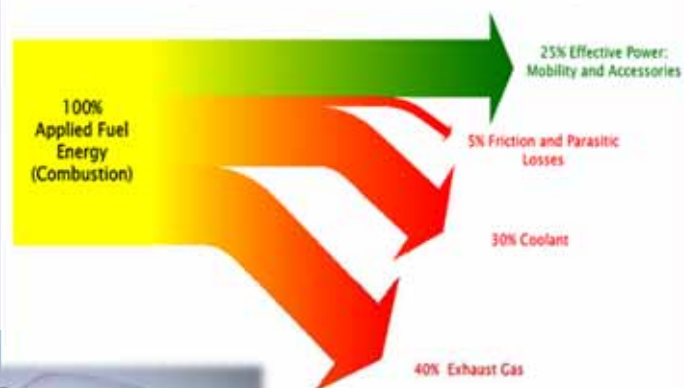


Hydrogen & Fuel Cells



Exhaust Waste Heat to Electrical Power

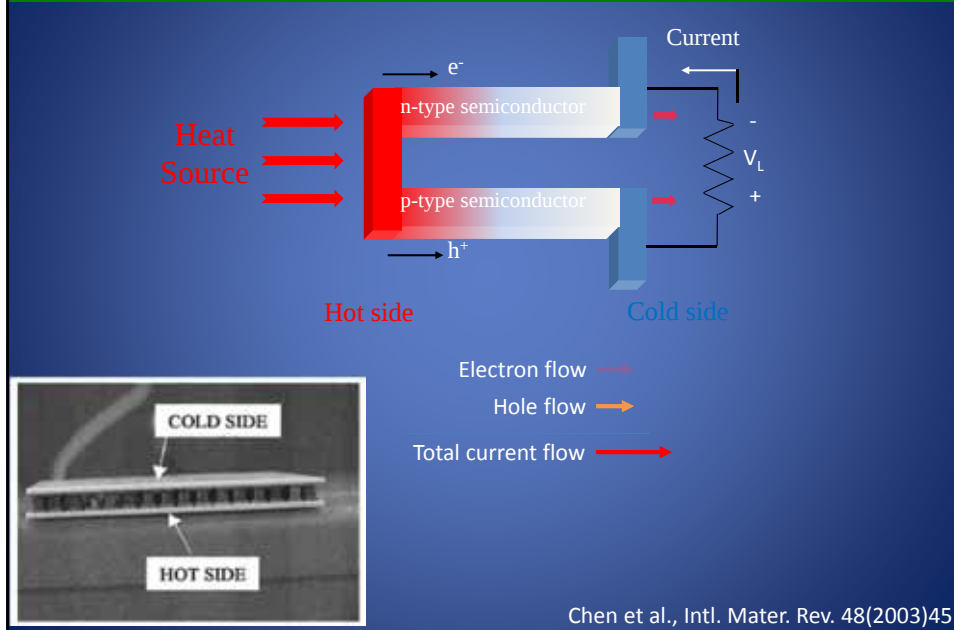
Typical Energy Split in Gasoline Internal Combustion Engines



GM has 350Watt avg systems on a truck can get 3% to 4% fuel saving with better integration.

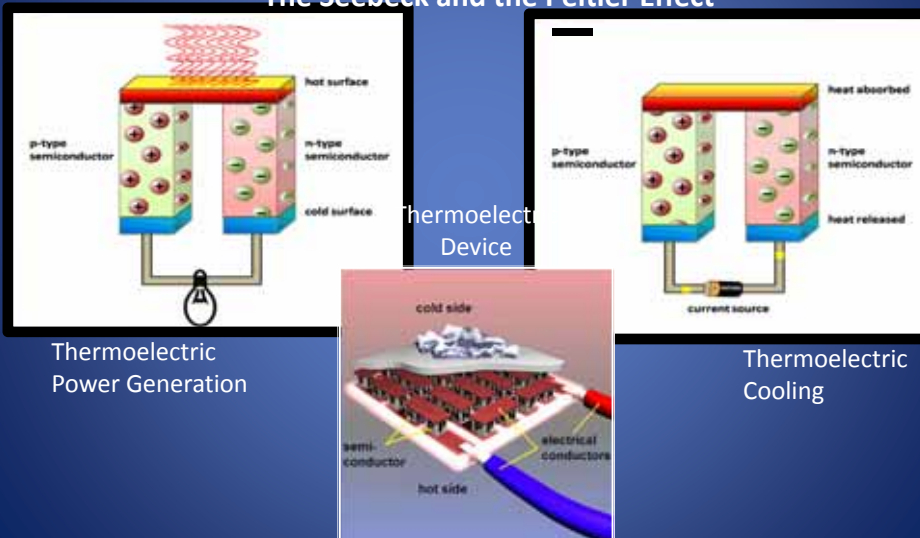
www.greencarcongress.com/thermoelectrics

TE Generator Working Principle

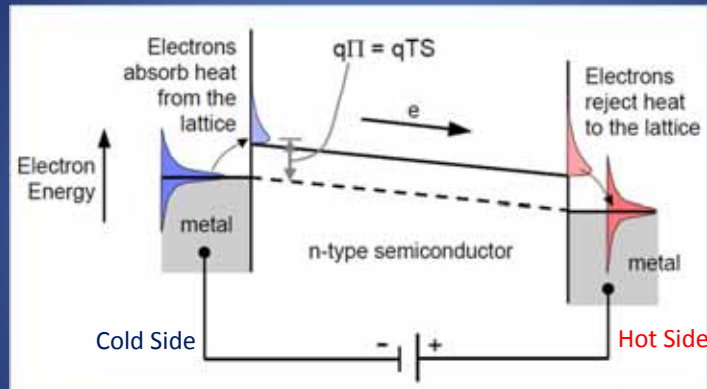


TE Generator Working Principle

The Seebeck and the Peltier Effect



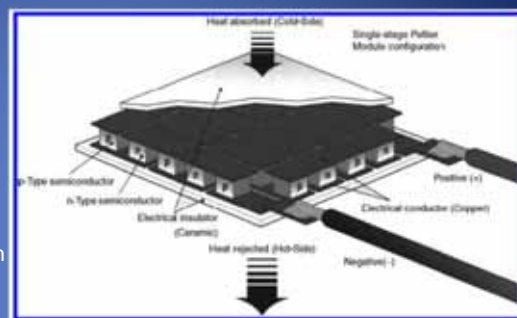
The Peltier Effect (1834)



Driven by an applied potential, electrons (holes) absorb heat from the lattice at the cold side, and reject heat to the lattice at the hot side
→ Refrigeration.

Benefits of Thermoelectric devices

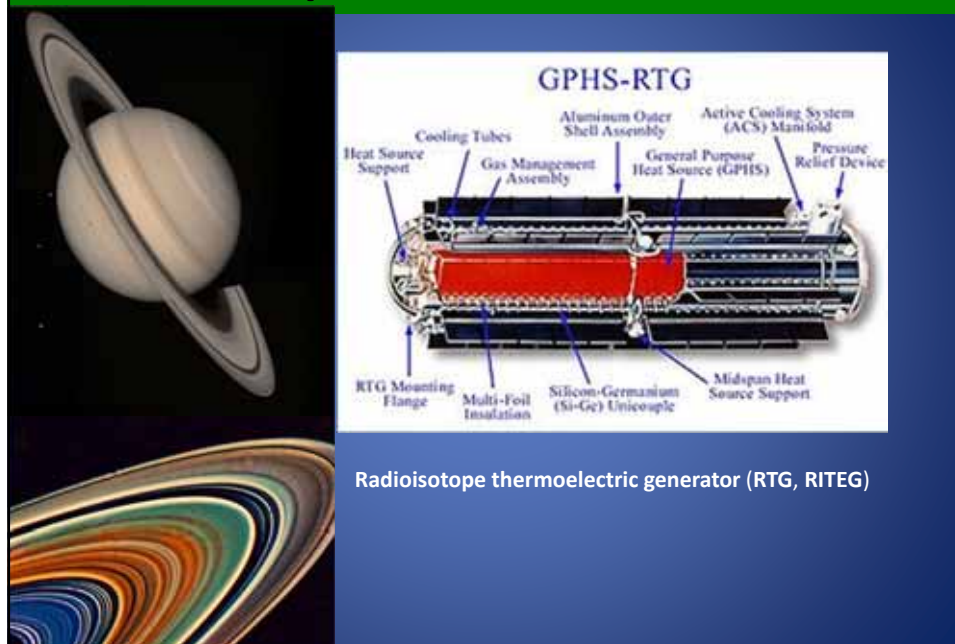
- ✓ No moving elements
- ✓ No working fluids and gases
- ✓ Low-noise operation
- ✓ Reduced size and weight
- ✓ High reliability — KRYOTHERM guarantees lifetimes of more than 200,000 hours for our TEDs
- ✓ Easy switching from cooling to heating mode



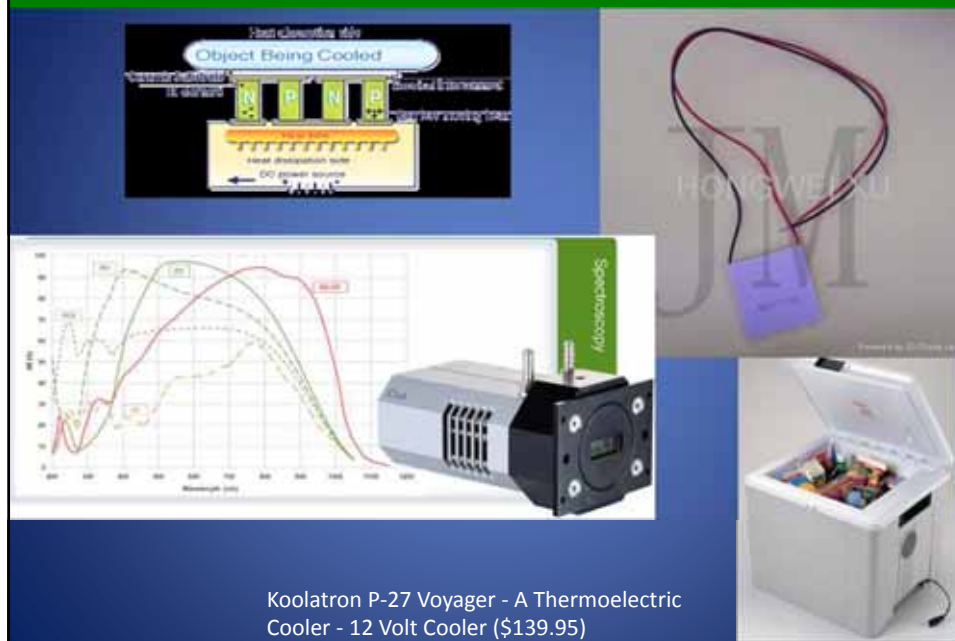
Example of TE Devices: Voyagers



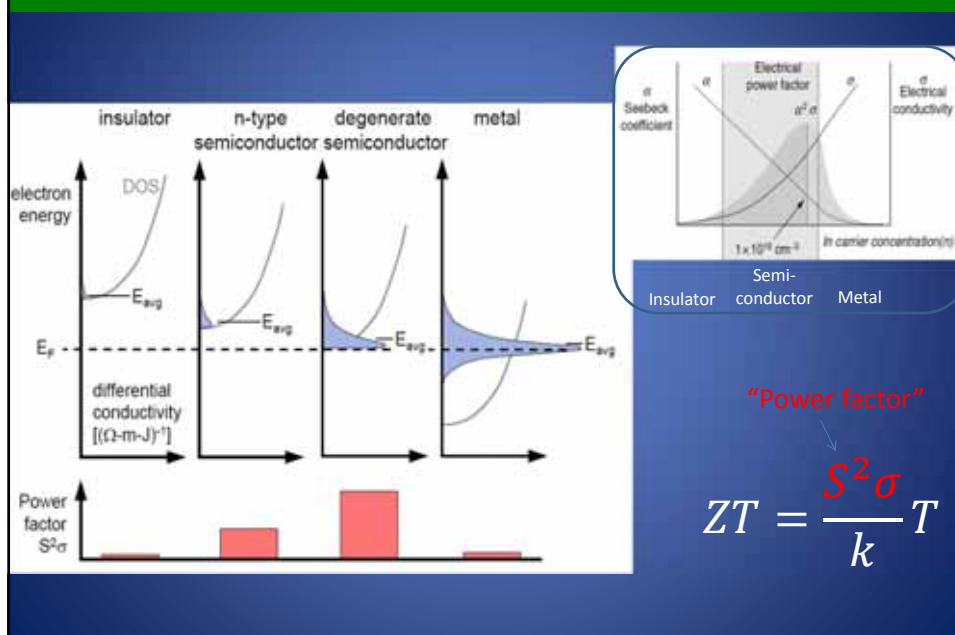
Example of TE Devices: RTG



Example of TE Devices: CCD Cooling



Differential Electron Conductivity



Selection of Thermoelectric Materials

$$Z = \frac{S^2 \sigma}{\kappa}$$

Electrical conductivity σ
Thermal conductivity κ
Seebeck coefficient S

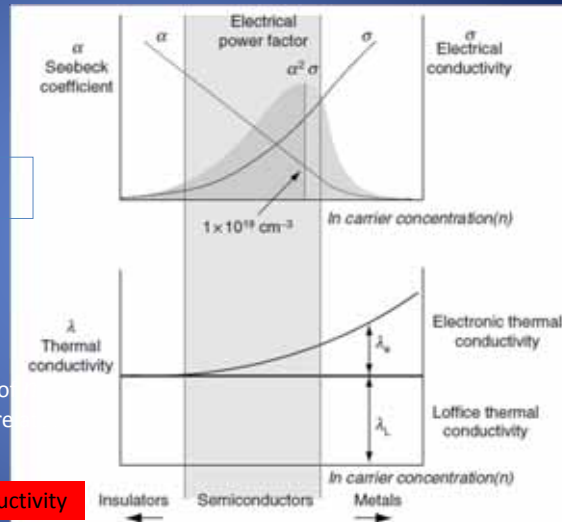
Free carrier
density n

The thermal conductivity

$$\kappa = \kappa_{\text{lattice}} + \kappa_{\text{electron}}$$

Lattice part is roughly independent of
while the electronic part is directly related
to the electrical conductivity

High power factor, Low thermal conductivity

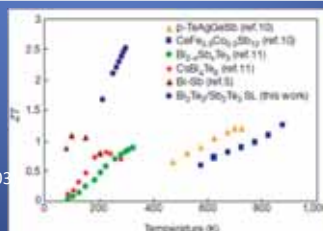


Schematic dependence of electrical conductivity, Seebeck coefficient, power factor, and thermal conductivity on concentration of free carriers.

ZT in This Decade

Year	Journal	Materials	ZT	T(K)	Institute
2011	Nature	PbTe _{1-x} Se _x (Buck)	1.8	850K	MS, California Institute of Technology
2009	Nature	In ₄ Se _{3-d} (Buck)	1.5	700K	Samsung
2008	Nature	Si (52nm rough NWs)	0.6	300K	Berkeley
2008	Nature	Si (20nm NWs)	1.0	200K	CE, California Institute of Technology
2008	Science	BiSeTe (buck)	1.5	400K	Physics, Boston College
2004	Science	AgPb _m SbTe _{2+m} (buck)	2.1	800K	Michigan State University
2003	Nature	Bi ₂ Te ₃ /Pb ₂ Te ₃ SL	2.6	300K	Research Triangle Institute
2002	Science	PbSeTe/PbTe SL	1.6	300K	Massachusetts Institute of Technology
Before			~1		

Y. Z Pei et al, Nature 473, 66 (2011)
J. S. Rhyee et al, Nature 459, 965 (2009)
A. I. Hochbaum et al, Nature 451, 163 (2008)
A. I. Boukai et al, Nature 451, 168 (2008)
B. Poudel et al, Science 320, 634 (2008)
K. F. Hsu et al, Science 303, 818 (2004)
R. Venkatasubramanian et al, Nature 413 597 (2003)
T. C. Harman et al, Science 297, 2229 (2002)



Nature Materials	Publication
2011	4
2010	4
2003-2009	13

ZT & Efficiency

Efficiency η

$$\eta = \frac{T_H - T_C}{T_H} \frac{\sqrt{1 + ZT} - 1}{\sqrt{1 + ZT} + T_C/T_H}$$

Figure-of-merit ZT

$$ZT = T \frac{S^2 \sigma}{\kappa}$$

Thermal conductivity κ

$$\kappa = \kappa_L + \kappa_{el}$$

Efficiency examples

ZT	T_H/K	T_C/K	η
0.5	673	373	5.6%
1	673	373	9.4%
2	673	373	14.3%
3	673	373	17.4%
3	773	373	20.8%
3	873	373	23.6%

Thermal conductivity κ

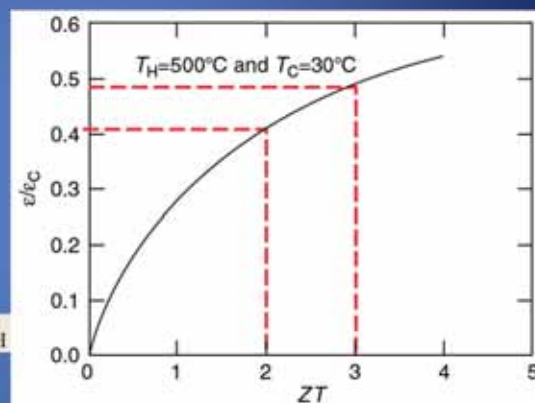
$$\kappa_{el} = L_0 \sigma T$$

- To match a refrigerator, an effective $ZT = 4$ is needed
- To efficiently recover waste heat from car, $ZT = 2$ is needed

Efficiency and ZT

$$\eta_{TE} = \eta_C \left(\frac{\sqrt{1 + ZT} - 1}{\sqrt{1 + ZT} + \frac{T_C}{T_H}} \right)$$

Carnot efficiency, $\eta_C = (T_H - T_C)/T_H$



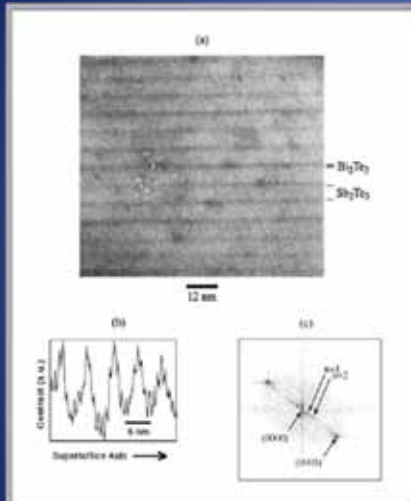
New Approaches

- New Bulk Materials
 - Skutterudites (Rensselaer, Oak Ridge, JPL, 1992)
 - ❖ Cage-structures with rattling atoms to scatter phonons
 - Novel Chalcogenides and Clathrates (Michigan State and Arizona, 1994)
 - ❖ Complex Variations of Bi_2Te_3 to reduce phonon mean-free paths
- Nano-scale Materials
 - Low-Dimensional Structures (MIT, MIT Lincoln Labs, 1992)
 - ❖ Quantum-confinement to Enhance Density of states which increase Seebeck coefficient
 - Nano-scale Superlattices (RTI, 1992)
 - ❖ **Phonon-blocking** from acoustic mismatch between superlattice components but **electron-transmitting** due to negligible electron-energy offsets
 - Heterostructure Thermionics (UCSB, Oak Ridge, 1996)
 - ❖ Thermionic-like effects using energy barriers that can be controlled in hetero-structures

New Progresses

- $\text{Cs Bi}_4\text{Te}_6$ (Michigan State University)
 - Bulk Materials with a $ZT \sim 0.8$ at 225K but less than 0.8 at 300K (*Science* **287**, 1024-1027, 2000)
- Filled Skutterudites (JPL)
 - Bulk materials with a $ZT \sim 1.35$ at 900K (Proc. Of 15th International Conf. On Thermoelectrics, 1996)
- PbTe/PbTeSe Quantum-dots (Harman, MIT Lincoln Labs.)
 - $ZT \sim 1.6$ at 300K based on cooling data (*Science* 297, Sep. 2002)
- $\text{Bi}_2\text{Te}_3/\text{Sb}_2\text{Te}_3$ Superlattices (RTI)
 - $ZT \sim 2.4$ at 300K in devices with all properties measured at the same place, same time, with current flowing and verified by two independent techniques (*Nature*, 597-602, Oct. 2001)

Nanostructured Superlattice

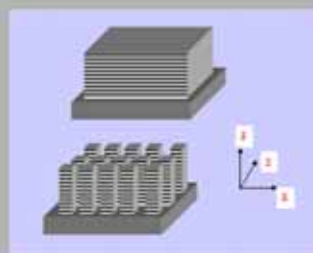


- 10Å/50Å $\text{Bi}_2\text{Te}_3/\text{Sb}_2\text{Te}_3$ Structure
- Optimized for disrupting heat transport while enhancing electron transport perpendicular to the superlattice interfaces

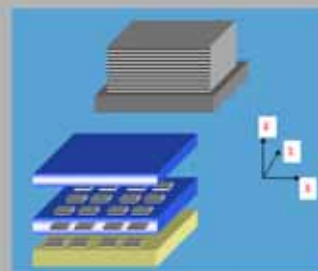
Applied Physics Letters, 75, 1104 (1999)

New Ideas

- Combine Phonon-Blocking, Electron-Transmitting Structures Along Heat Flow with Orthogonal Quantum-Confinement for ZT in the range of 4 to 5?

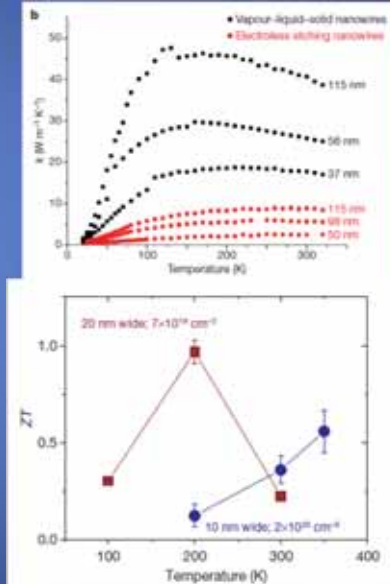
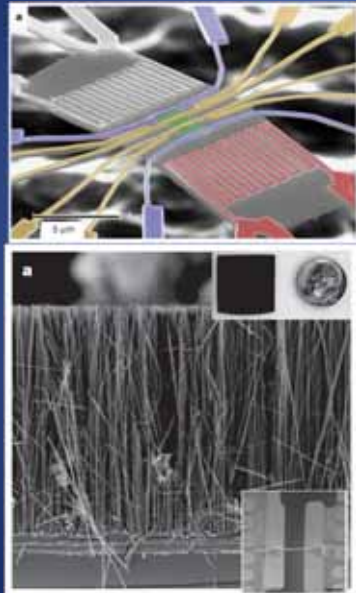


Layered SL Patterned to form 1-d Quantum-Wires – **Orthogonal Quantum Confinement**

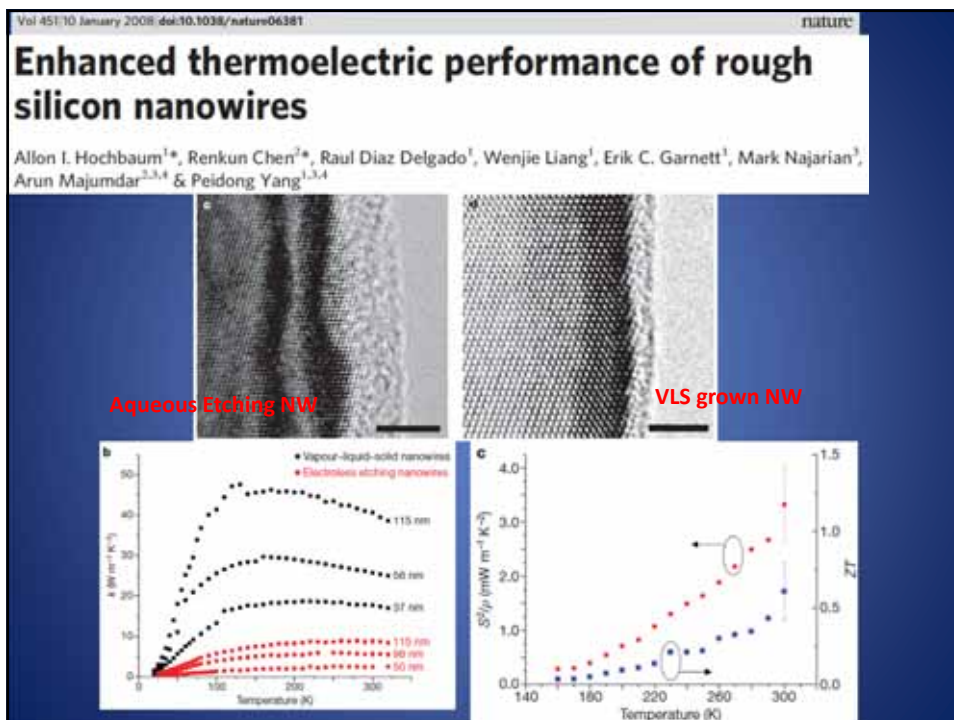


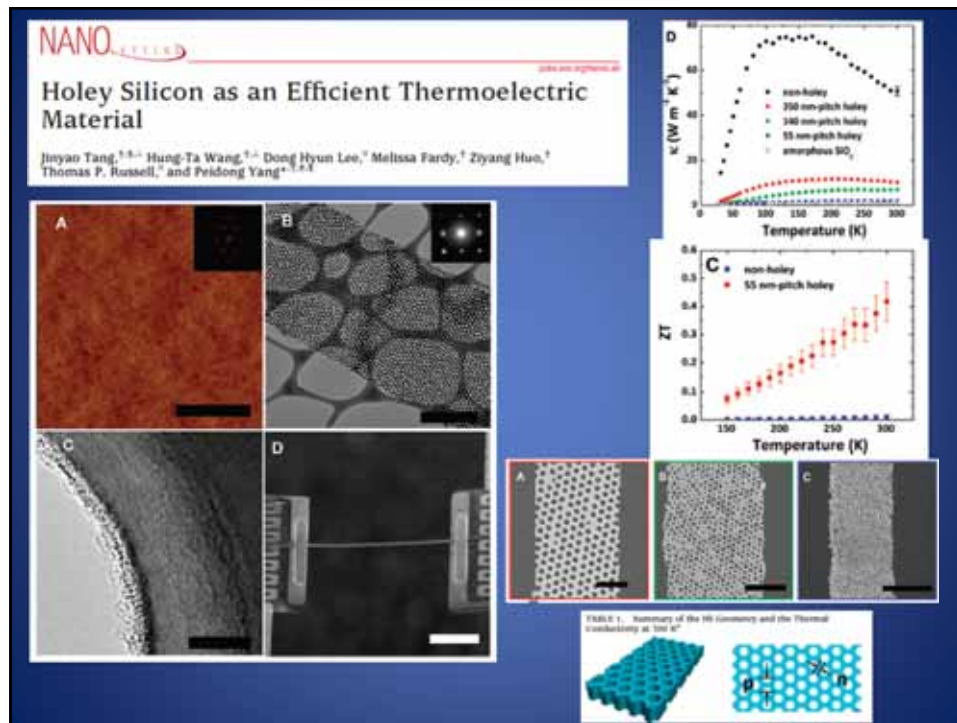
Layered SL Patterned to form Quantum-Boxes – **Orthogonal Quantum Confinement**

Si Nanowires as an Efficient TE Material

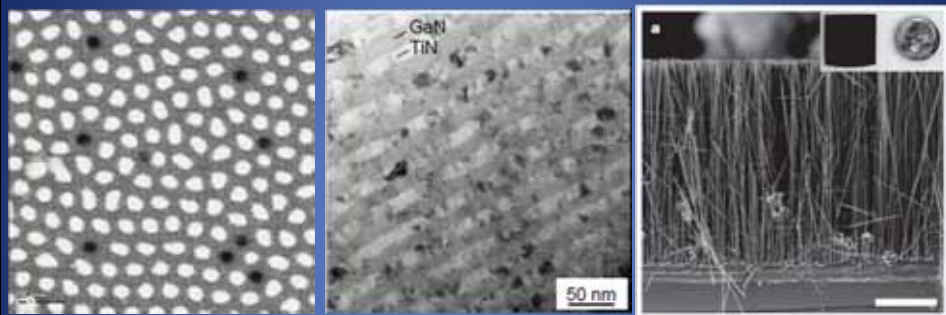


Akram I. Boukai *et al*, Nature **451** 168(2007)





Nano-composite & Nanowires



Nano-composite

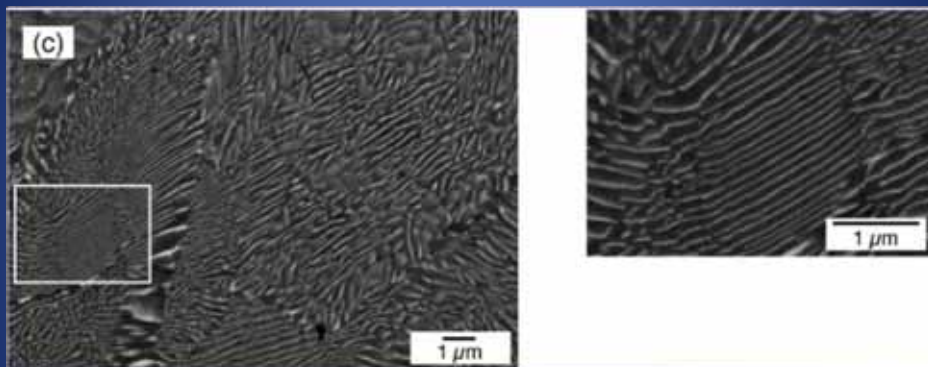
Super-lattice structure

Nanowires

Goal: Reduce Thermal conductivity or
Increase electrical conductivity

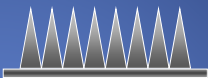
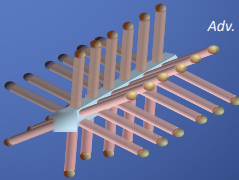
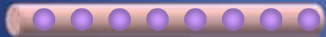
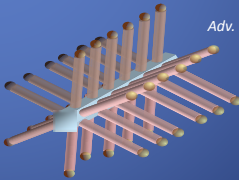
T. Sands et al, Purdue University
Akram I. Boukai et al, Nature **451** 168(2007)

Lamellae of Thermoelectric PbTe and Sb₂Te₃

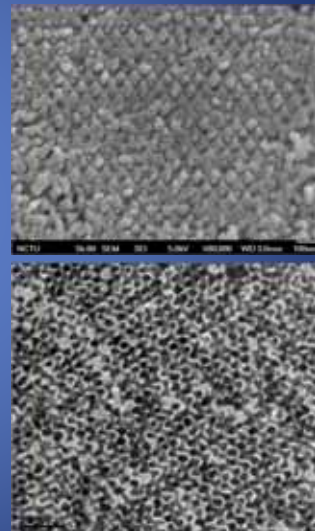
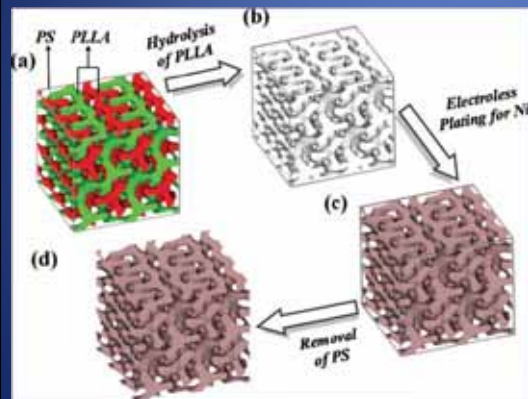


Jeffrey Snyder *Chem. Mater.*, Vol. 19, No. 4, 2007 765

1-D Nano Materials in AML

JACS 123, 2791 (2001) APL 81, 22 (2002) JACS 127, 2820 (2005) APL 90, 213104 (2007) Adv. Func. Mater. (2008) Small 4, 925 (2008) Electrochem. Comm. 11, 850 (2009) Anal. Chem. 81, 36 (2009) Angew. Chem. Int. Ed. 49, 5966 (2010) APL 81, 4189 (2002) Adv. Func. Mater. 12, 687 (2002) APL 86, 203119 (2005) JACS 128, 8368 (2006) PRB 75, 195429 (2007) J. Power Sources 171, 55 (2007) JACS 130, 3543 (2008) J. Power Sources 190, 279 (2009) Chapter 9, pp. 259-309, <i>Nanowires and nanobelts</i>, Kluwer (2004) Adv. Func. Mater. 16, 537 (2006) APL 90, 123109 (2007) Adv. Mater. 19, 4524 (2007) Opt. Express 17, 11690 (2009) Adv. Mater. 14, 1847 (2002) Nature Mater. 5, 102 (2006)	Wire/Rod 	Nanotip 	APL 83, 1420 (2003) Nano. Lett. 4, 471 (2004) Chem. Mater. 17, 553 (2005) Adv. Func. Mater. 15, 783 (2005) APL 86, 203119 (2005) US Patent 6,960,528,B2 APL 89, 143105 (2006) Nature Nanotech. 2, 170 (2007) Nano Lett. 9, 1938 (2009)
APL 81, 4189 (2002) Adv. Func. Mater. 12, 687 (2002) APL 86, 203119 (2005) JACS 128, 8368 (2006) PRB 75, 195429 (2007) J. Power Sources 171, 55 (2007) JACS 130, 3543 (2008) J. Power Sources 190, 279 (2009)	Tube 	Core-shell 	APL 81, 1312 (2002) Nano. Lett. 3, 537 (2003)
Chapter 9, pp. 259-309, <i>Nanowires and nanobelts</i>, Kluwer (2004) Adv. Func. Mater. 16, 537 (2006) APL 90, 123109 (2007) Adv. Mater. 19, 4524 (2007) Opt. Express 17, 11690 (2009)	Belt 	Brush 	Adv. Func. Mater. 14, 233 (2004)
Adv. Mater. 14, 1847 (2002) Nature Mater. 5, 102 (2006)	Peapod 	Brush 	Other related: APL 86, 21911 (2005) APL 86, 83104 (2005) APL 86, 161901 (2005) APL 87, 261915 (2005) JVST B 24, 87 (2006) APL 88, 73515 (2006) Adv. Mater. 21, 259 (2009) Angew. Chem. 48, 7586 (2009) J. Mater. Chem. (2010)

Nanocomposites



TE Measurement



Multiwall carbon nanotube



Silver nanowire



ZnO nanowire



Ga₂O₃ nanowire



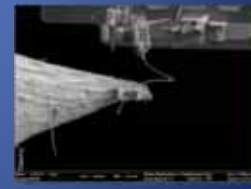
Undoped Si nanowire



P-type Si nanowire



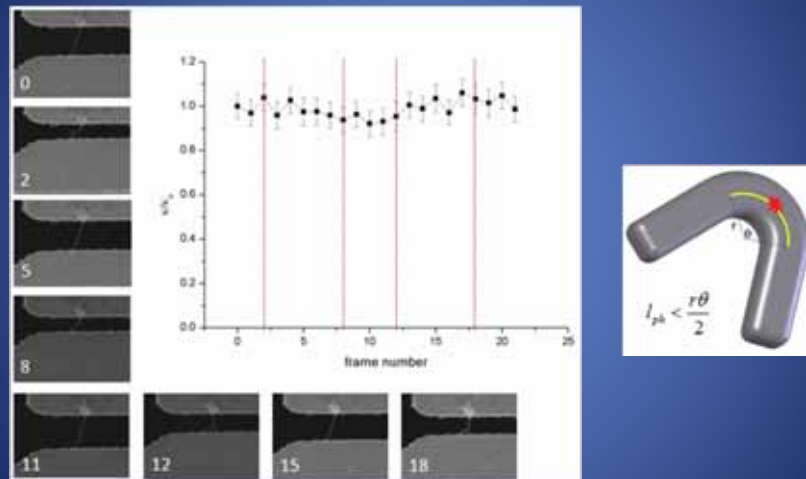
N-type Si nanowire



SiGe nanowire

Thermal conductivities remain intact under extreme strain

SWCNT goes beyond the theoretical limit of 1D ballistic phonon transport



No changes of thermal conductivity is observed even when the bending radius of curvature is less than the phonon mean free path.

Perspective



- Nanotechnology provides great opportunity for Thermoelectric materials.
- Demonstration of high ZT materials is yet to come.